SN74BCT29843 9-BIT BUS-INTERFACE D-TYPE LATCH WITH 3-STATE OUTPUTS

SCBS022C - FEBRUARY 1989 - REVISED NOVEMBER 1993

- BiCMOS Process With CMOS Inputs and TTL Outputs Substantially Reduces Standby Current
- Input Has 50 kΩ
- Package Options Include Plastic Small-Outline (DW) Packages and Standard Plastic 300-mil DIPs (NT)

description

The SN74BCT29843 features 3-state outputs designed specifically for driving highly capacitive or relatively low-impedance loads. It is particularly suitable for implementing wider buffer registers, I/O ports, bidirectional bus drivers with parity, and working registers.

(TOP VIEW)						
OE [1	U	24	vcc		
1D[2		23] 1Q		
2D [3		22	2Q		
3D [4		21] 3Q		
4D [5		20] 4Q		
5D [6		19] 5Q		
6D [7		18] 6Q		
7D [8		17] 7Q		
8D [9		16] 8Q		
9D [10		15] 9Q		
CLR [11		14	PRE		
GND[12		13	LE		

DW OR NT PACKAGE

The nine latches are transparent D-type latches. When the latch-enable (LE) input is high, the Q outputs are complementary to the noninverting data (D) inputs.

A buffered output-enable (\overline{OE}) input can be used to place the nine outputs in either a normal logic state (high or low level) or a high-impedance state. In the high-impedance state, the outputs neither load nor drive the bus lines significantly. The high-impedance state and increased drive provide the capability to drive bus lines without need for interface or pull-up components.

The output enable (\overline{OE}) does not affect the internal operation of the flip-flops. Old data can be retained or new data can be entered while the outputs are in the high-impedance state.

The SN74BCT29843 is characterized for operation from 0°C to 70°C.

FUNCTION TABLE

	INPUTS				
PRE	CLR	OE	LE	D	Q
L	Х	L	Х	Χ	Н
Н	L	L	X	Χ	L
Н	Н	L	Н	L	L
Н	Н	L	Н	Н	Н
Н	Н	L	L	Χ	Q ₀
X	X	Н	Χ	Χ	Z

SN74BCT29843 9-BIT BUS-INTERFACE D-TYPE LATCH **WITH 3-STATE OUTPUTS**

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EN

S2

R

C1

1D

 \triangleright

logic symbol†

14

11

13

2

3

4

5

6

7

8

9

10

OE

PRE

CLR

LE

1D

2D

3D

4D

5D

6D

7D

8D

9D

23 2♡ 1Q 22 2Q 21 3Q 20 4Q 19 50

18

17

16

15

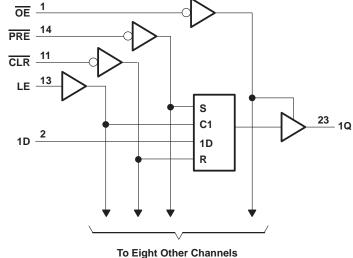
60

7Q

8Q

9Q

logic diagram (positive logic)



[†] This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)‡

Supply voltage range, V _{CC}	$\ldots \ldots -0.5~V$ to 7 V
Input voltage range, V _I (see Note 1)	$\ldots \ldots -0.5~V$ to 7 V
Voltage range applied to any output in the disabled or power-off state, V _O	$\ldots \ldots -0.5~V$ to 7 V
Voltage range applied to any output in the high state, V _O	$\dots \dots -0.5 \text{ V to V}_{CC}$
Input clamp current, I _{IK} (V _I < 0)	–30 mÅ
Current into any output in the low state, I _O	96 mA
Operating free-air temperature range	0°C to 70°C
Storage temperature range	– 65°C to 150°C

[‡] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. This is a stress rating only, and functional operation of the device at these or any other conditions beyond those indicated in the "recommended operating conditions" section of this specification is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability. NOTE 1: The input and output negative-voltage ratings may be exceeded if the input and output clamp-current ratings are observed.

recommended operating conditions

		MIN	NOM	MAX	UNIT
Vcc	Supply voltage	4.5	5	5.5	V
VIH	High-level input voltage	2			V
V _{IL}	Low-level input voltage			0.8	V
lik	Input clamp current			-18	mA
lOH	High-level output current			-24	mA
lOL	Low-level output current			48	mA
TA	Operating free-air temperature	0		70	°C



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electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP [†]	MAX	UNIT
VIK	$V_{CC} = 4.5 \text{ V},$	I _I = -18 mA			-1.2	V
Vou	V _{CC} = 4.5 V	$I_{OH} = -15 \text{ mA}$	2.4	3.2		V
VOH	VCC = 4.5 V	$I_{OH} = -24 \text{ mA}$	2			V
VOL	$V_{CC} = 4.5 \text{ V},$	I _{OL} = 48 mA		0.35	0.55	V
lį	V _{CC} = 5.5 V,	V _I = 7 V			0.1	mA
lн	$V_{CC} = 5.5 \text{ V},$	V _I = 2.7 V	-10		-75	μΑ
I _{IL}	$V_{CC} = 5.5 \text{ V},$	V _I = 0.4 V			-0.2	mA
los [‡]	$V_{CC} = 5.5 V$,	V _O = 0	-75		-275	mA
ICCL	$V_{CC} = 5.5 V$,	Outputs open		24	35	mA
Іссн	$V_{CC} = 5.5 \text{ V},$	Outputs open		3	7	mA
Iccz	$V_{CC} = 5.5 V$,	Outputs open		3	7	mA

[†] All typical values are at $V_{CC} = 5 \text{ V}$, $T_A = 25^{\circ}\text{C}$.

timing requirements over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

			MIN	MAX	UNIT
t _W		PRE low	7		
	Pulse duration CLR low		5		ns
	L	LE high	4		
t _{su}	Setup time, data before LE↓	High or low	1.5		ne
	Setup time, data before LEV	PRE or CLR inactive	2		ns
t _h	Hold time, data after LE↓	High or low	3.5		ns

switching characteristics over recommended ranges of supply voltage and operating free-air temperature, C_L = 50 pF (unless otherwise noted) (see Note 2)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{CC} = 5 V, T _A = 25°C			MIN	MAX	UNIT
	(INFOT)	(0011-01)	MIN	TYP	MAX			
^t PLH	D	Q	1.5	4.5	7	1.5	8	ns
^t PHL	ט	Q	1.5	5.7	8	1.5	9	115
^t PLH	LE	Q	1.5	6	8	1.5	10	ns
^t PHL		Q	1.5	6	8	1.5	10	115
t _{PLH}	PRE	Q	1.5	6	8	1.5	12	ns
^t PHL		Q	1.5	6	10	1.5	12	115
^t PLH	01.0	Q	1.5	6	10	1.5	12	20
^t PHL	CLR	Q	1.5	6	10	1.5	12	ns
^t PZH		0	2	10	13	2	15	20
t _{PZL}	ŌĒ	Q	2	10	13	2	15	ns
^t PHZ	ŌĒ	Q	2	5	7	2	8	200
t _{PLZ}		ų ,	2	5	7	2	8	ns

NOTE 2: Load circuits and voltage waveforms are shown in Section 1.



[‡] Not more than one output should be tested at a time, and the duration of the test should not exceed one second.

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